

**SKIIP 31 NAB 06**

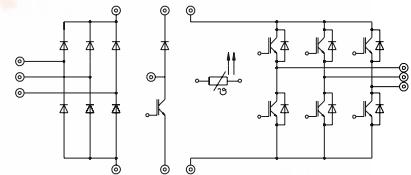
<b>Absolute Maximum Ratings</b>		<b>Values</b>	<b>Units</b>
<b>Symbol</b>	<b>Conditions<sup>1)</sup></b>		
Inverter			
$V_{CES}$		600	V
$V_{GES}$		$\pm 20$	V
$I_C$	$T_{heatsink} = 25 / 80^\circ\text{C}$	50 / 35	A
$I_{CM}$	$t_p < 1 \text{ ms}; T_{heatsink} = 25 / 80^\circ\text{C}$	100 / 70	A
$I_F = -I_C$	$T_{heatsink} = 25 / 80^\circ\text{C}$	57 / 38	A
$I_{FM} = -I_{CM}$	$t_p < 1 \text{ ms}; T_{heatsink} = 25 / 80^\circ\text{C}$	114 / 76	A
Bridge Rectifier			
$V_{RRM}$		800	V
$I_D$	$T_{heatsink} = 80^\circ\text{C}$	25	A
$I_{FSM}$	$t_p = 10 \text{ ms}; \sin. 180^\circ, T_j = 25^\circ\text{C}$	370	A
$I^2t$	$t_p = 10 \text{ ms}; \sin. 180^\circ, T_j = 25^\circ\text{C}$	680	A <sup>2</sup> s
$T_j$		-40 ... +150	°C
$T_{stg}$		-40 ... +125	°C
$V_{isol}$	AC, 1 min.	2500	V

**MiniSKiiP 3**  
**SEMIKRON integrated intelligent Power**  
**SKIIP 31 NAB 06**  
**3-phase bridge rectifier + braking chopper + 3-phase bridge inverter**

Case M3



<b>Characteristics</b>		<b>min.</b>	<b>typ.</b>	<b>max.</b>	<b>Units</b>
<b>Symbol</b>	<b>Conditions<sup>1)</sup></b>				
IGBT - Inverter					
$V_{CEsat}$	$I_C = 50 \text{ A}, T_j = 25 (125)^\circ\text{C}$	-	2,1(2,2)	2,7(2,8)	V
$t_{d(on)}$	$V_{CC} = 300 \text{ V}; V_{GE} = \pm 15 \text{ V}$	-	60	120	ns
$t_r$	$I_C = 50 \text{ A}; T_j = 125^\circ\text{C}$	-	80	160	ns
$t_{d(off)}$	$R_{gon} = R_{goff} = 22 \Omega$	-	330	500	ns
$t_f$	inductive load	-	550	830	ns
$E_{on} + E_{off}$		-	7,3	-	mJ
$C_{ies}$	$V_{CE} = 25 \text{ V}; V_{GE} = 0 \text{ V}, 1 \text{ MHz}$	-	2,8	-	nF
$R_{thjh}$	per IGBT	-	-	1,0	K/W
IGBT - Chopper *					
$V_{CEsat}$	$I_C = 30 \text{ A}, T_j = 25 (125)^\circ\text{C}$	-	2,1(2,2)	2,7(2,8)	V
$t_{d(on)}$	$V_{CC} = 300 \text{ V}; V_{GE} = \pm 15 \text{ V}$	-	50	100	ns
$t_r$	$I_C = 30 \text{ A}; T_j = 125^\circ\text{C}$	-	80	160	ns
$t_{d(off)}$	$R_{gon} = R_{goff} = 33 \Omega$	-	250	370	ns
$t_f$	inductive load	-	500	750	ns
$E_{on} + E_{off}$		-	4,0	-	mJ
$C_{ies}$	$V_{CE} = 25 \text{ V}; V_{GE} = 0 \text{ V}, 1 \text{ MHz}$	-	1,6	-	nF
$R_{thjh}$	per IGBT	-	-	1,4	K/W
Diode <sup>2)</sup> - Inverter & Chopper					
$V_F = V_{EC}$	$I_F = 50 \text{ A}, T_j = 25 (125)^\circ\text{C}$	-	1,45(1,4)	1,7(1,7)	V
$V_{TO}$	$T_j = 125^\circ\text{C}$	-	0,85	0,9	V
$r_T$	$T_j = 125^\circ\text{C}$	-	11	16	mΩ
$I_{RRM}$	$I_F = 50 \text{ A}, V_R = -300 \text{ V}$	-	50	-	A
$Q_{rr}$	$dI_F/dt = -800 \text{ A}/\mu\text{s}$	-	5,0	-	μC
$E_{off}$	$V_{GE} = 0 \text{ V}, T_j = 125^\circ\text{C}$	-	1,5	-	mJ
$R_{thjh}$	per diode	-	-	1,2	K/W
Diode - Rectifier					
$V_F$	$I_F = 25 \text{ A}, T_j = 25^\circ\text{C}$	-	1,2	-	V
$R_{thjh}$	per diode	-	-	2,6	K/W
Temperature Sensor					
$R_{TS}$	$T = 25 / 100^\circ\text{C}$	1000 / 1670		$\Omega$	
Mechanical Data					
$M_1$	case to heatsink, SI Units	2	-	2,5	Nm
Case	mechanical outline see page B 16 - 9	M3			



UL recognized file no. E63532

- specification of temperature sensor see part A
- common characteristics see page B16-3

**Options**

- also available with faster IGBTs (type ... 063), data sheet on request

<sup>1)</sup>  $T_{heatsink} = 25^\circ\text{C}$ , unless otherwise specified

<sup>2)</sup> CAL = Controlled Axial Lifetime Technology (soft and fast recovery)

For diagrams of the Chopper IGBT please refer to SKiiP 22 NAB 06



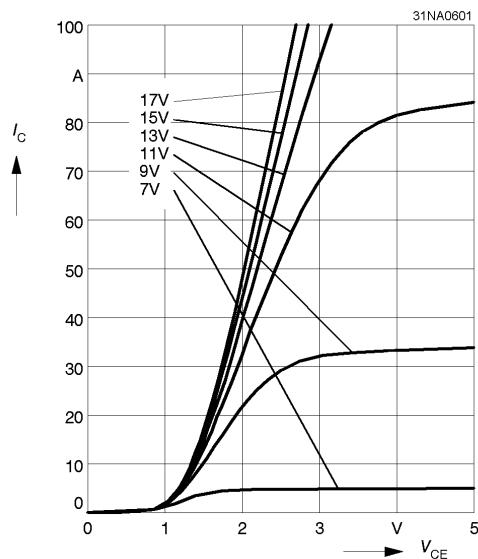


Fig. 1 Typ. output characteristic,  $t_p = 80 \mu s$ ;  $25^\circ C$

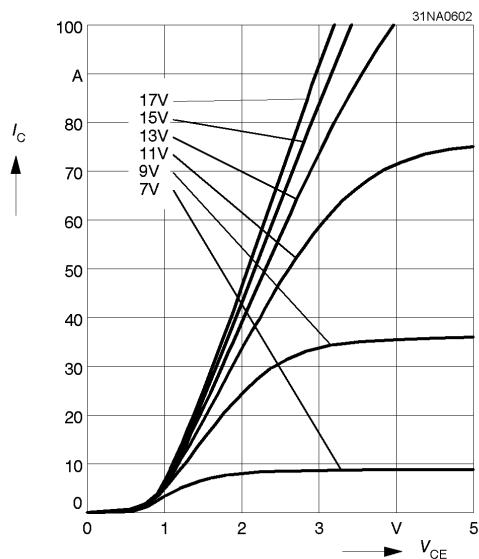


Fig. 2 Typ. output characteristic,  $t_p = 80 \mu s$ ;  $125^\circ C$

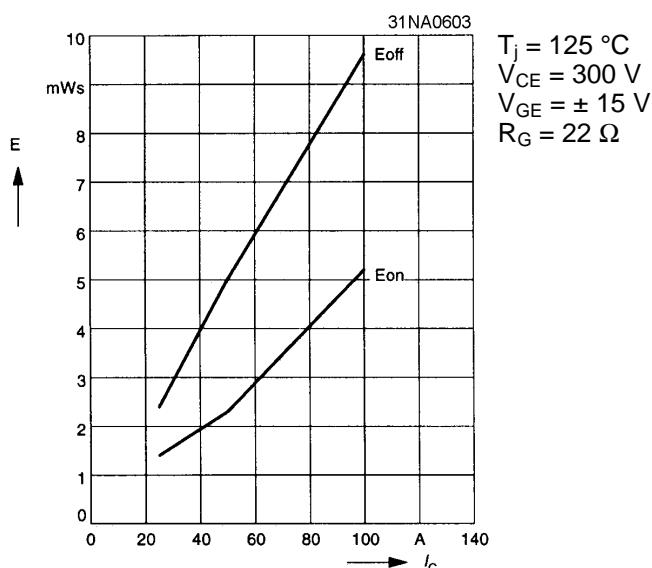


Fig. 3 Turn-on / -off energy = f ( $I_C$ )

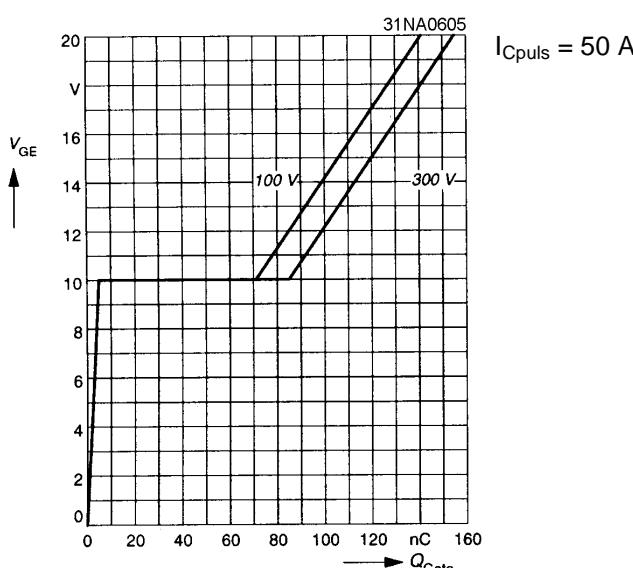


Fig. 5 Typ. gate charge characteristic

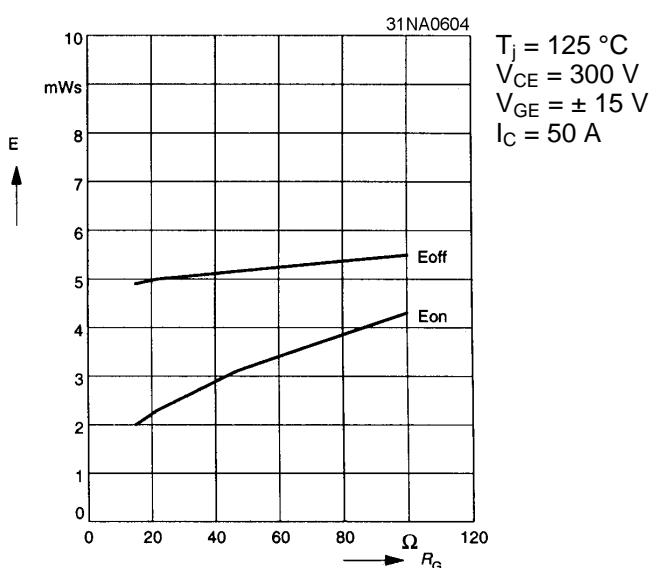


Fig. 4 Turn-on / -off energy = f ( $R_G$ )

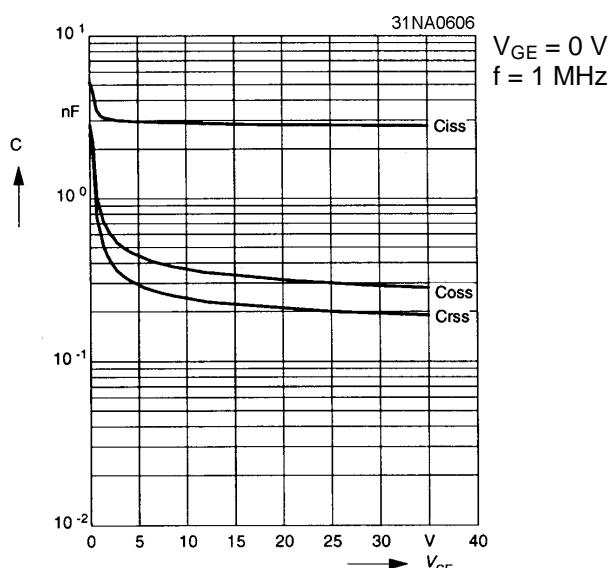


Fig. 6 Typ. capacitances vs.  $V_{CE}$

## 2. Common characteristics of MiniSKiiP

### MiniSKiiP 600 V

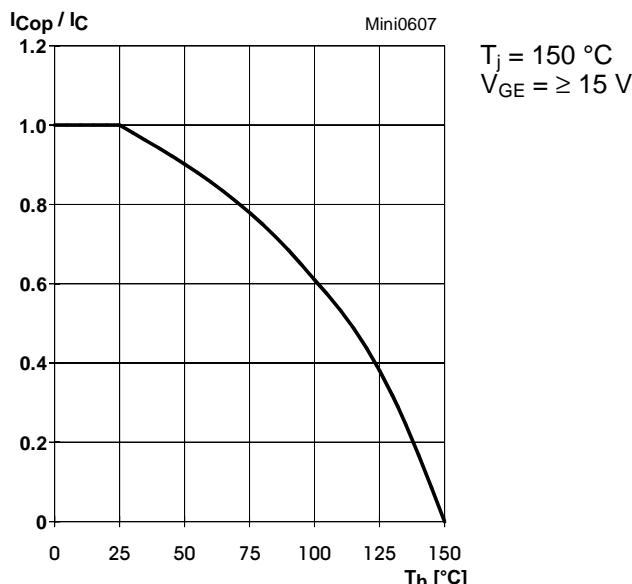


Fig. 7 Rated current of the IGBT  $I_{C_{op}} / I_C = f(T_j)$

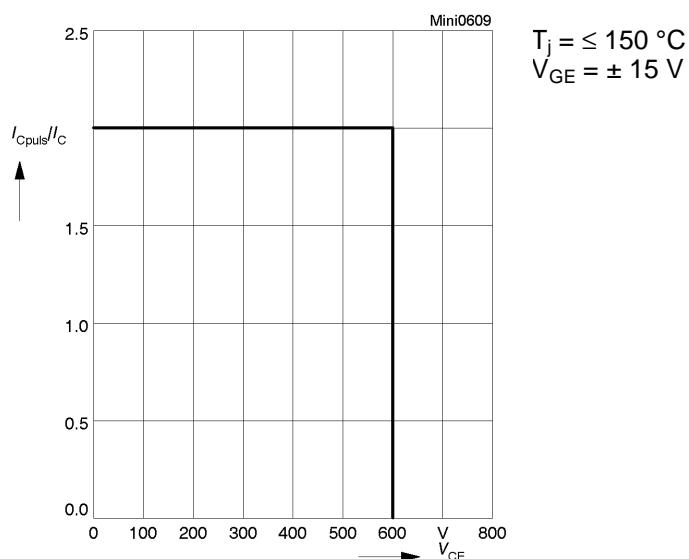


Fig. 9 Turn-off safe operating area (RBSOA) of the IGBT

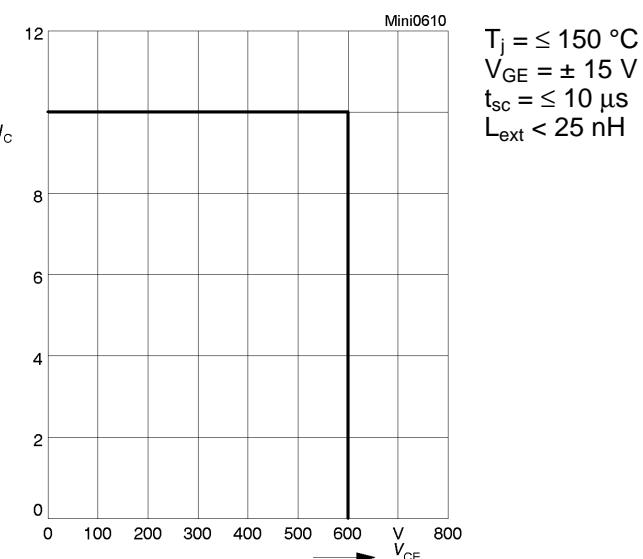


Fig. 10 Safe operating area at short circuit of the IGBT

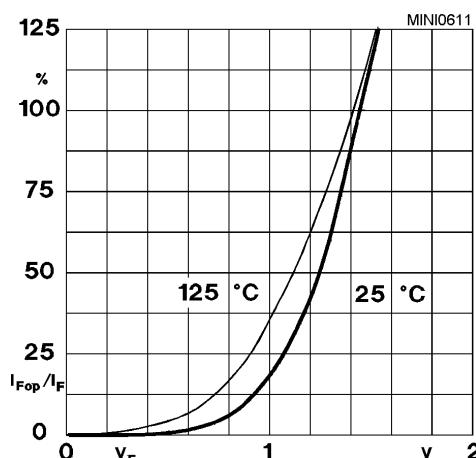


Fig. 11 Typ. freewheeling diode forward characteristic

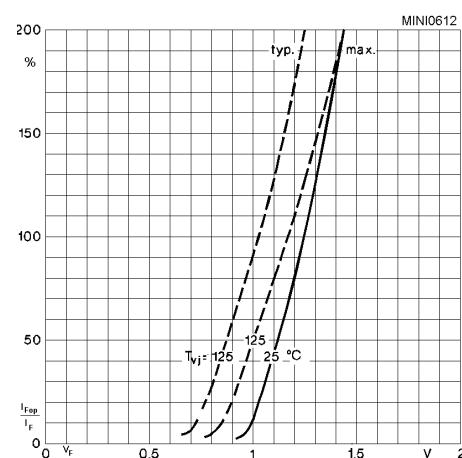


Fig. 12 Forward characteristic of the input bridge diode

### MiniSKiiP 3

SKiiP 30 NAB 06      Circuit  
 SKiiP 31 NAB 06      Case M3  
 SKiiP 32 NAB 06      Layout and connections for the  
 SKiiP 30 NAB 12      customer's printed circuit board  
 SKiiP 31 NAB 12  
 SKiiP 32 NAB 12

